HD74LVU04A

Hex Inverters

HITACHI

ADE-205-248 (Z)
1st Edition
March 1999

Description

The HD74LVU04A has six inverters with unbuffered outputs in a 14-pin package.
Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- V_{CC} = 2.0 V to 5.5 V operation
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- All outputs V_O (Max.) = 5.5 V (@V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Output current ±6 mA (@V_{CC} = 3.0 V to 3.6 V), ±12 mA (@V_{CC} = 4.5 V to 5.5 V)

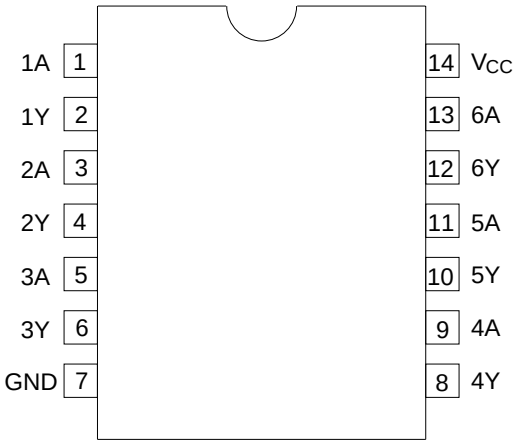
Function Table

Input A	Output Y
H	L
L	H

Note: H: High level
L: Low level

Hitachi semiconductor

Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V_{CC}	–0.5 to 7.0	V	
Input voltage range*[1]	V_I	–0.5 to 7.0	V	
Output voltage range*[1, 2]	V_O	–0.5 to V_{CC} + 0.5	V	Output: H or L
Input clamp current	I_{IK}	–20	mA	$V_I < 0$
Output clamp current	I_{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	±25	mA	V_O = 0 to V_{CC}
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air)*[3]	P_T	785	mW	SOP
		500		TSSOP
Storage temperature	Tstg	–65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

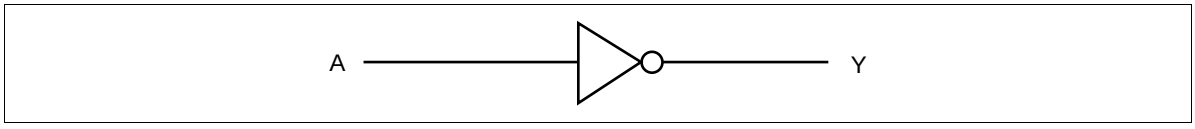
1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	2.0	5.5	V	
Input voltage range	V_I	0	5.5	V	
Output voltage range	V_O	0	V_{CC}	V	
Output current	I_{OH}	—	–50	µA	V_{CC} = 2.0 V
		—	–2	mA	V_{CC} = 2.3 to 2.7 V
		—	–6		V_{CC} = 3.0 to 3.6 V
		—	–12		V_{CC} = 4.5 to 5.5 V
	I_{OL}	—	50	µA	V_{CC} = 2.0 V
		—	2	mA	V_{CC} = 2.3 to 2.7 V
		—	6		V_{CC} = 3.0 to 3.6 V
		—	12		V_{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	–40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

- **Ta = –40 to 85°C**

Item	Symbol	V_{CC} (V)*	Min	Typ	Max	Unit	Test Conditions
Input voltage	V_{IH}	2.0	1.7	—	—	V	
		2.3 to 2.7	$V_{CC} \times 0.8$	—	—		
		3.0 to 3.6	$V_{CC} \times 0.8$	—	—		
		4.5 to 5.5	$V_{CC} \times 0.8$	—	—		
	V_{IL}	2.0	—	—	0.3		
		2.3 to 2.7	—	—	$V_{CC} \times 0.2$		
		3.0 to 3.6	—	—	$V_{CC} \times 0.2$		
		4.5 to 5.5	—	—	$V_{CC} \times 0.2$		
Output voltage	V_{OH}	Min to Max	V_{CC} – 0.1	—	—	V	I_{OL} = –50 µA
		2.3	2.0	—	—		I_{OL} = –2 mA
		3.0	2.48	—	—		I_{OL} = –6 mA
		4.5	3.8	—	—		I_{OL} = –12 mA
	V_{OL}	Min to Max	—	—	0.1	V	I_{OL} = 50 µA
		2.3	—	—	0.4		I_{OL} = 2 mA
		3.0	—	—	0.44		I_{OL} = 6 mA
		4.5	—	—	0.55		I_{OL} = 12 mA
Input current	I_{IN}	0 to 5.5	—	—	±1	µA	V_{IN} = 5.5 V or GND
Quiescent supply current	I_{CC}	5.5	—	—	20	µA	V_{IN} = V_{CC} or GND, I_O = 0
Input capacitance	C_{IN}	3.3	—	4.0	—	pF	V_I = V_{CC} or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

- $V_{CC} = 2.5 \pm 0.2$ V

		Ta = 25°C			Ta = –40 to 85°C					
Item	**Symbol**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**	**FROM (Input)**	**TO (Output)**
Propagation delay time	t_{PLH} t_{PHL}	—	3.2	10.9	1.0	14.0	ns	C_L = 15 pF	A	Y
		—	6.6	13.4	1.0	16.0		C_L = 50 pF		

- $V_{CC} = 3.3 \pm 0.3$ V

		Ta = 25°C			Ta = –40 to 85°C					
Item	**Symbol**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**	**FROM (Input)**	**TO (Output)**
Propagation delay time	t_{PLH} t_{PHL}	—	2.5	8.9	1.0	10.5	ns	C_L = 15 pF	A	Y
		—	4.7	11.4	1.0	13.0		C_L = 50 pF		

- $V_{CC} = 5.0 \pm 0.5$ V

		Ta = 25°C			Ta = –40 to 85°C					
Item	**Symbol**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**	**FROM (Input)**	**TO (Output)**
Propagation delay time	t_{PLH} t_{PHL}	—	2.2	5.5	1.0	6.5	ns	C_L = 15 pF	A	Y
		—	3.9	7.0	1.0	8.0		C_L = 50 pF		

Operating Characteristics

- **C_L = 50 pF**

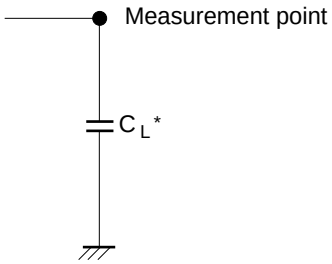
			Ta = 25°C				
Item	**Symbol**	**V_{cc} (V)**	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
Power dissipation capacitance	C_{PD}	3.3	—	5.6	—	pF	f = 10 MHz
		5.0	—	6.7	—		

Noise Characteristics

- **C_L = 50 pF**

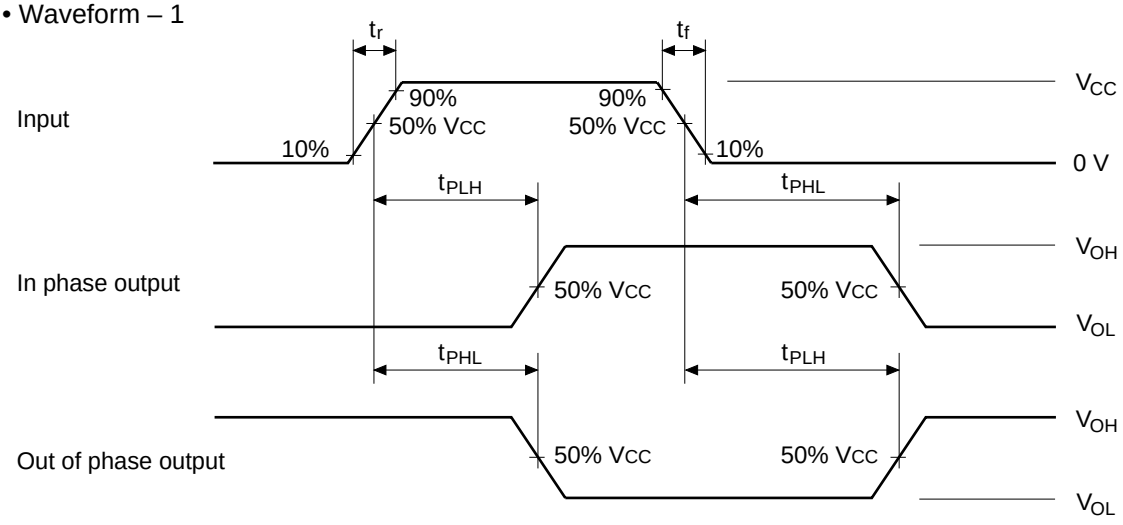
			Ta = 25°C				
Item	**Symbol**	**V_{cc} (V)**	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
Quiet output, maximum dynamic V_{OL}	$V_{OL (P)}$	3.3	—	0.5	0.8	V	
Quiet output, minimum dynamic V_{OL}	$V_{OL (V)}$	3.3	—	–0.1	–0.8		
Quiet output, minimum dynamic V_{OH}	$V_{OH (V)}$	3.3	—	3.0	—		
High-level dynamic put voltage	$V_{IH (D)}$	3.3	2.31	—	—	V	
Low-level dynamic put voltage	$V_{IL (D)}$	3.3	—	—	0.99		

Test Circuit



Note: C_L includes the probe and jig capacitance.

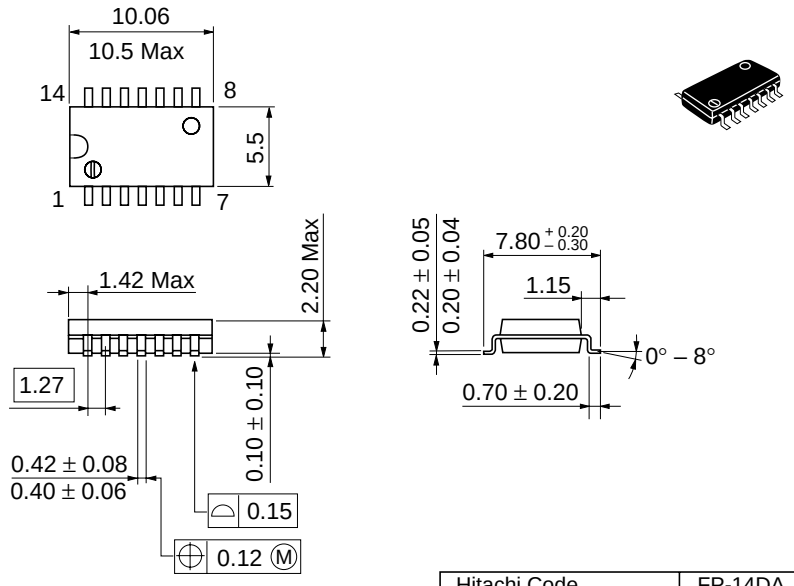
• Waveform – 1



Notes: 1. Input waveform: PRR ≤ 1 MHz, Zo = 50 Ω, $t_r \leq 3$ ns, $t_f \leq 3$ ns
2. The output are measured one at a time with one transition per measurement.

Package Dimensions

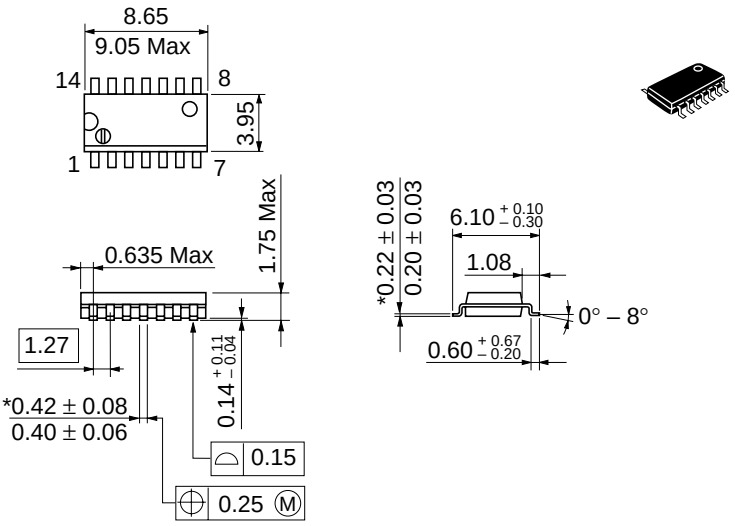
Unit: mm



Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.23 g

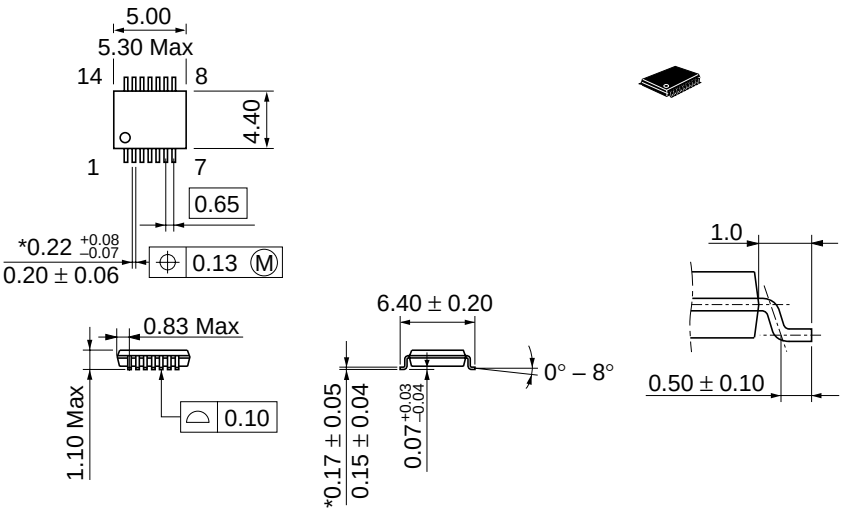
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.13 g

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-14D
JEDEC	—
EIAJ	—
Weight (reference value)	0.05 g

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